



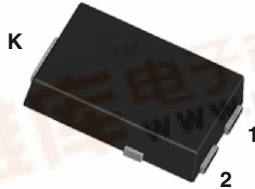
V12P10

Vishay General Semiconductor

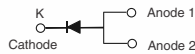
High Current Density Surface Mount Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.43\text{ V}$ at $I_F = 5\text{ A}$

TMBS® eSMP™ Series



TO-277A (SMPC)



FEATURES

- Very low profile - typical height of 1.1 mm
- Ideal for automated placement
- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- **Halogen-free**



RoHS COMPLIANT HALOGEN FREE

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	12 A
V_{RRM}	100 V
I_{FSM}	200 A
E_{AS}	100 mJ
V_F at $I_F = 12\text{ A}$	0.58 V
T_J max.	150 °C

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters and polarity protection applications.

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94V-0 flammability rating.

Base P/N-E3 - RoHS compliant, commercial grade
Base P/NHE3 - RoHS compliant, high reliability/automotive grade (AEC-Q101 qualified)

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, high reliability/automotive grade (AEC-Q101 qualified)

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test, HE3 and HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V12P10	UNIT
Device marking code		V1210	
Maximum repetitive peak reverse voltage	V_{RRM}	100	V
Maximum average forward rectified current (Fig. 1)	$I_{F(AV)}$	12	A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I_{FSM}	200	A
Non-repetitive avalanche energy at $I_{AS} = 2.0\text{ A}$, $T_J = 25\text{ °C}$	E_{AS}	100	mJ
Operating junction and storage temperature range	T_J, T_{STG}	- 40 to + 150	°C





ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	$I_R = 1.0\text{ mA}$	$T_A = 25\text{ }^\circ\text{C}$	V_{BR}	100 (minimum)	-	V
Instantaneous forward voltage ⁽¹⁾	$I_F = 5\text{ A}$ $I_F = 12\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	V_F	0.50 0.65	- 0.70	V
	$I_F = 5\text{ A}$ $I_F = 12\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.43 0.58	- 0.64	
Reverse current ⁽²⁾	$V_R = 70\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$ $T_A = 125\text{ }^\circ\text{C}$	I_R	7.0 4.4	- -	μA mA
	$V_R = 100\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$ $T_A = 125\text{ }^\circ\text{C}$		21.3 11.8	250 20	μA mA

Notes:

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V12P10	UNIT
Typical thermal resistance	$R_{\theta JA}$ ⁽¹⁾	60	$^\circ\text{C/W}$
	$R_{\theta JL}$	3	

Note:

- (1) Units mounted on recommended P.C.B. 1 oz. pad layout

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
V12P10-E3/86A	0.10	86A	1500	7" diameter plastic tape and reel
V12P10-E3/87A	0.10	87A	6500	13" diameter plastic tape and reel
V12P10HE3/86A ⁽¹⁾	0.10	86A	1500	7" diameter plastic tape and reel
V12P10HE3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel
V12P10-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel
V12P10-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel
V12P10HM3/86A ⁽¹⁾	0.10	86A	1500	7" diameter plastic tape and reel
V12P10HM3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel

Note:

- (1) High reliability/automotive grade (AEC-Q101 qualified)



RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

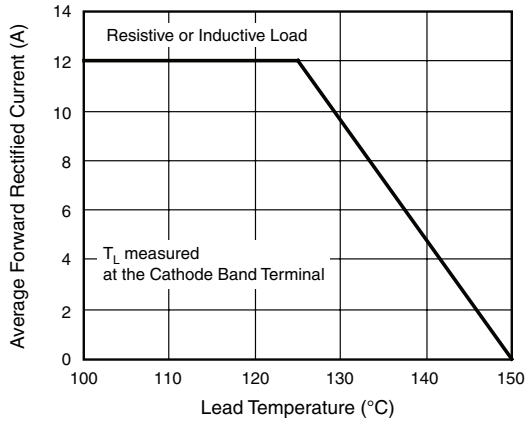


Figure 1. Maximum Forward Current Derating Curve

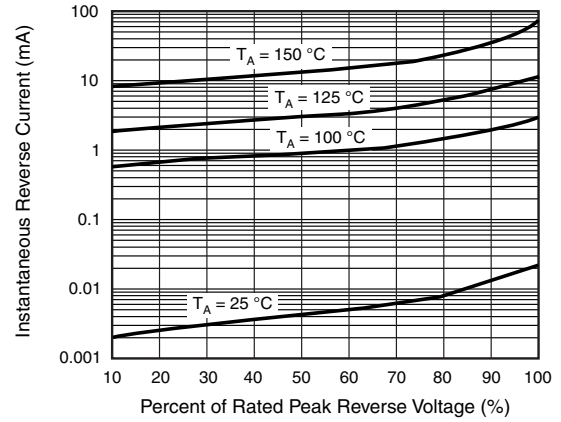


Figure 4. Typical Reverse Characteristics

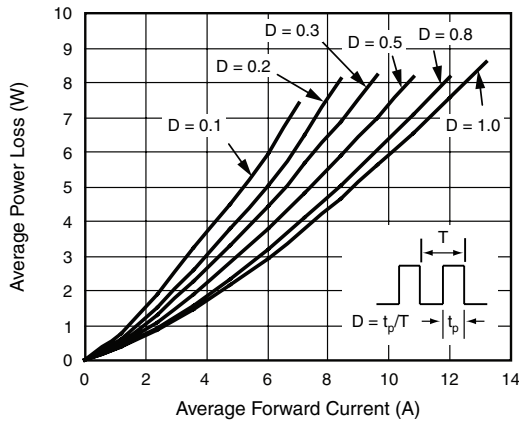


Figure 2. Forward Power Loss Characteristics

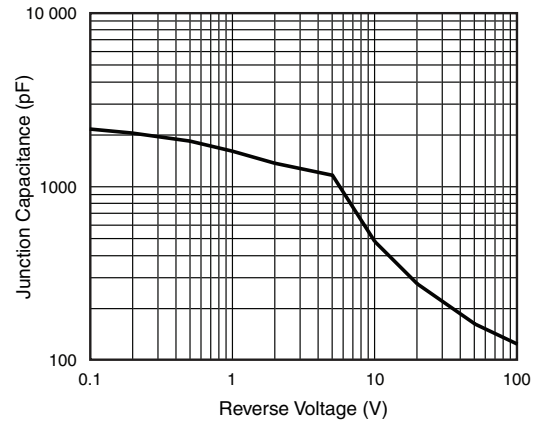


Figure 5. Typical Junction Capacitance

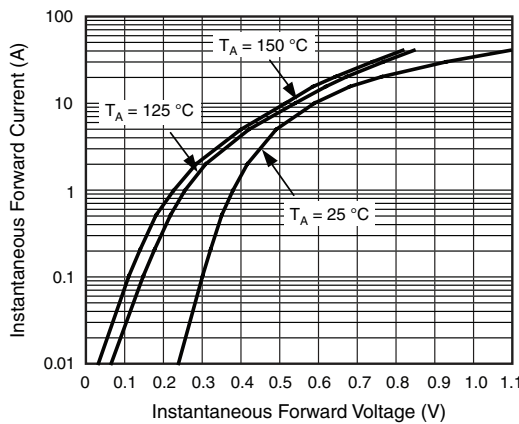


Figure 3. Typical Instantaneous Forward Characteristics

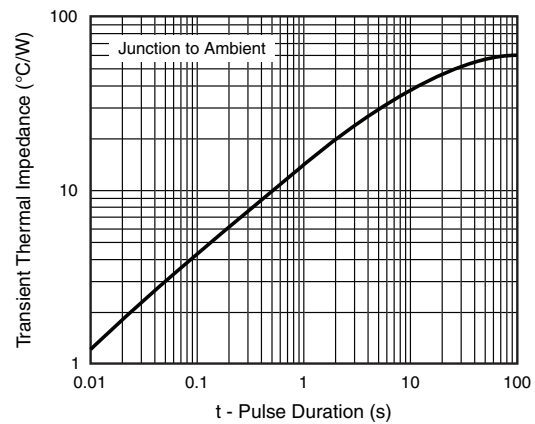


Figure 6. Typical Junction Thermal Impedance

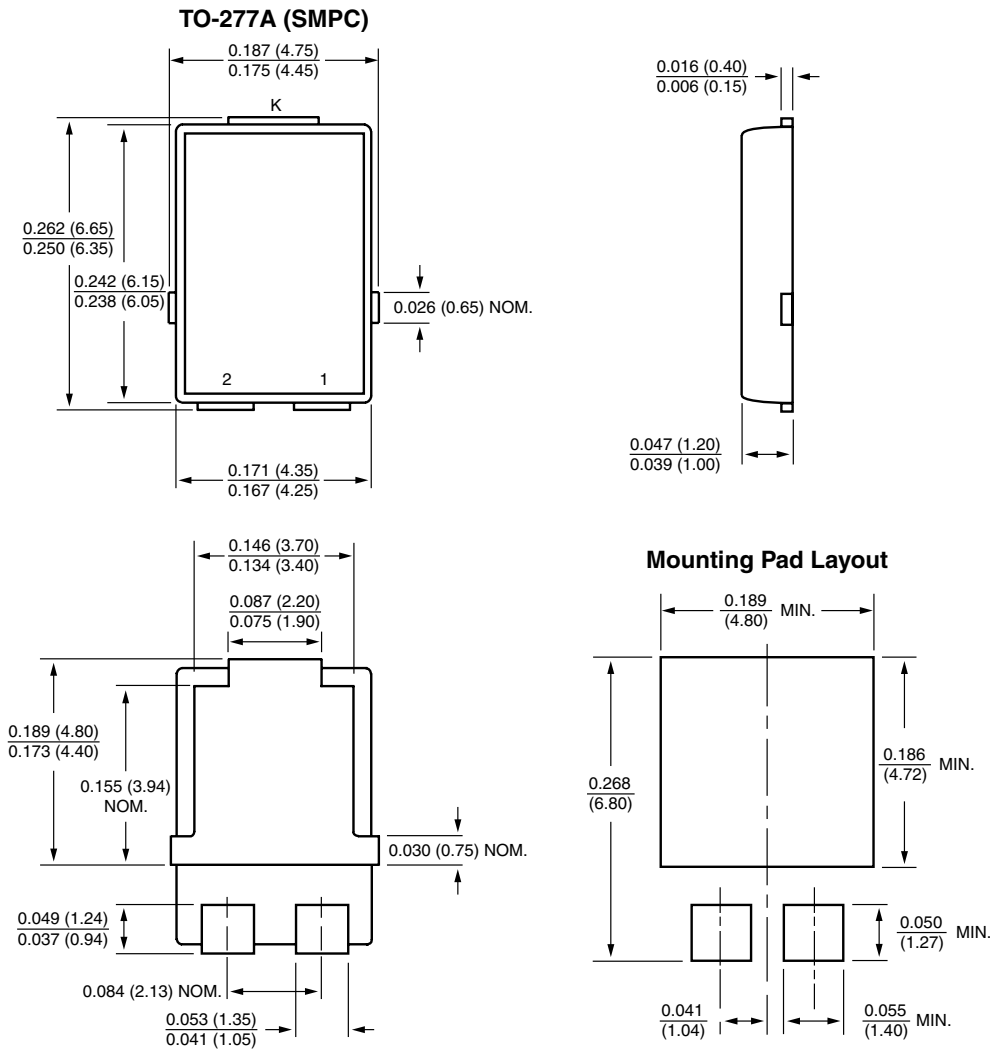
V12P10

New Product



Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Conform to JEDEC TO-277A



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